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Interoffice Memorandum

To
J. Lohr
Department
Code 311
From
K. Sahu KS
Department
7809
Subject
Radiation Report on ISTEP/WAVES
Part No. FRL9130R3

PPM-91-534
Date
August 22, 1991
Location
GSFC
Telephone
731-8954
Location
Lanham
cc
R. Sharma
S. Esmacher

A radiation evaluation was performed on FRL9130 to determine the total dose tolerance of these parts. A brief summary of the test results is provided below. For detailed information, refer to Tables I through IV and Figure 1.

The total dose testing was performed using a cobalt-60 gamma ray source. Parts were separated into two test groups of five parts each. In each group, four parts were irradiated and one part was used as a control sample. During the radiation testing, Test Group A (TGA) parts were irradiated without bias, while Test Group B (TGB) parts were irradiated under bias (see Figure 1 for bias configuration). The total dose radiation steps were 2.5, 5, 7.5, 10, 15, 20, 30 and 50 krads. After 50 krads, parts were annealed at 25°C for 24 and 168 hours (cumulative), and then irradiation was continued to 100, 200 and 300 krads. The dose rate was between 0.1 - 5.0 krads/hour, depending on the total dose level (see Table II for radiation schedule). After each radiation exposure and annealing treatment, parts were electrically tested according to the test conditions and the specification limits listed in Table III.

All (4) parts in Test Group A and three parts in Test Group B passed all tests on irradiation up to 300 krads. However, SN 221 from Test Group B did not initially pass the AC tests (TDon, TDoFF, Tr and Tf) after 7.5 krads, but passed these tests on retest, twenty minutes later. The same part was also observed to momentarily fail the AC tests after 50 krads, but again passed on retest. The control samples passed all tests at all radiation and annealing steps. Tables IVA and IVB provide the mean and standard deviation values for each parameter after different radiation exposures and annealing treatments for Test Group A and Test Group B, respectively.

Any further details about this evaluation can be obtained upon request. If you have any questions, please call me at (301) 731-8954.

TABLE I. Part Information

Generic Part Number:	FRL9130
ISTP/WAVES Part Number:	FRL9130R3
ISTP/WAVES Control Number:	4578
Charge Number:	C14433
Manufacturer:	Harris Corp.
Lot Date Code:	9029
Quantity Tested:	10
Serial Numbers of Radiation Samples:	203, 205, 211, 212 (TGA) 220, 221, 222, 223 (TGB)
Serial Numbers of Control Samples:	200 (TGA) 219 (TGB)
Part Function:	P-Channel Power MOSFET
Part Technology:	MOSFET
Package Style:	TO-205
Test Engineer:	Anh Phung

TABLE II. Radiation Schedule for TGA and TGB

EVENTS	DATE
1) Initial Electrical Measurements	07/09/91
2) 2.5 krad irradiation @ 125 rads/hr Post 2.5 krad Electrical Measurements	07/15/91 07/16/91
3) 5 krad irradiation @ 125 rads/hr Post 5 krad Electrical Measurements	07/16/91 07/17/91
4) 7.5 krad irradiation @ 125 rads/hr Post 7.5 krad Electrical Measurements	07/17/91 07/18/91
5) 10 krad irradiation @ 125 rads/hr Post 10 krad Electrical Measurements	07/18/91 07/19/91
6) 15 krad irradiation @ 75 rads/hr Post 15 krad Electrical Measurements	07/19/91 07/22/91
7) 20 krad irradiation @ 250 rads/hr Post 20 krad Electrical Measurements	07/22/91 07/23/91
8) 30 krad irradiation @ 500 rads/hr Post 30 krad Electrical Measurements	07/23/91 07/24/91
9) 50 krad irradiation @ 1000 rads/hr Post 50 krad Electrical Measurements	07/24/91 07/25/91
10) 24 hour annealing Post 24 hr Electrical Measurements	07/25/91 07/26/91
11) 168 hour annealing Post 168 hr Electrical Measurements	07/25/91 08/01/91
12) 100 krad irradiation @ 2500 rads/hr Post 100 krad Electrical Measurements	08/01/91 08/02/91
13) 200 krad irradiation @ 1470 rads/hr Post 200 krad Electrical Measurements	08/02/91 08/05/91
14) 300 krad irradiation @ 5000 rads/hr Post 300 krad Electrical Measurements	08/05/91 08/06/91

Notes:

- All parts ^{IN TGB} were radiated under bias at the cobalt-60 gamma ray facility at GSFC.
- All electrical measurements were performed off-site at 25°C.
- Annealing performed at 25°C under bias.

of parts in TGB

Table III. Electrical Characteristics of FRL9130

$T_A = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED

NO.	PARAMETER	TEST CONDITION	MIN	MAX	UNIT	METHOD
1	BV_{DSS}	$V_{GS} = 0$ $I_D = 1\text{mA}$	-100		V	3407
2	$V_{GS(th)}$	$V_{DS} = V_{GS}$ $I_D = 1\text{mA}$	-2	-4	V	3403
3	I_{GSSF}	$V_{GS} = -20\text{V}$		100	nA	3411
4	I_{GSSR}	$V_{GS} = +20\text{V}$		100	nA	3411
5	I_{DSS1}	$V_{DS} = -100\text{V}$ $V_{GS} = 0$		1	mA	3413
6	I_{DSS2}	$V_{DS} = -80\text{V}$ $V_{GS} = 0$		25	μA	3413
7	$V_{DS(on)}$	$V_{GS} = -10\text{V}$ $I_D = 5\text{A}$, PULSED *		-2.89	V	3405
8	$R_{DS(on)}$	$V_{GS} = -10\text{V}$ $I_D = 3\text{A}$, PULSED *		0.55	Ω	3421
9	V_{GD}	$V_{GD} = 0$ $I_D = 5\text{A}$, PULSED *	-0.6	-1.8	V	4011
10	$t_{D(on)}$	$V_{DD} = -50\text{V}$, $PW = 3\mu\text{s}$, $PER = 300\text{ms}$ $I_D = 5\text{A}$, $R_{GEN} = 25\Omega$, $0 \leq V_{GS} \leq -10\text{V}$		56	nS	3472
11	$t_{D(off)}$	—#—		126	nS	3472
12	t_r	—#—		124	nS	3472
13	t_f	—#—		78	nS	3472
1	I_{DSS3}	$V_{DS} = -80\text{V}$ $V_{GS} = 0$, $T_A = 125^\circ\text{C}$				3413

DELTA LIMITS: $\Delta I_{GSSF} = \pm 20\text{nA}$ OR $\pm 100\%$, WHICHEVER IS GREATER.

$\Delta I_{DSS2} = \pm 15\mu\text{A}$ OR $\pm 100\%$, WHICHEVER IS GREATER.

$\Delta V_{GS(th)} = \pm 20\%$

* $t_{pulse} = 800\mu\text{s}$, DUTY CYCLE = 2% SEE ATTACHED MEMO.

TABLE IVA: Summary of Electrical Measurements
after Total Dose Exposures and Annealing for FRL9130

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Group A - Parts irradiated without bias

Parameters		Spec. Limits		Initials		Total Dose Exposure (krads)													
						2.5		5		7.5		10		15		20		30	
		min	max	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd
V _{DSS(-)}	V	100	-	Pass		Pass		Pass		Pass		Pass		Pass		Pass		Pass	
V _{GS-h(-)}	V	2	4	3.4	.03	3.5	.03	3.5	.02	3.5	.03	3.5	.02	3.5	.02	3.5	.03	3.5	.01
I _{GSSF}	nA	-	100	1.2	.03	1.1	.03	1.2	.03	1.4	.06	1.2	.04	1.6	.03	1.3	.09	1.4	.1
I _{GSSR}	nA	-	100	.4	.07	.1	.04	.2	0	.4	.04	.4	.06	.2	.03	.3	.06	.3	.06
I _{DSS1}	mA	-	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
I _{DSS2}	uA	-	25	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
R _{DS on}	mOhm	-	550	249	1	252	4	248	2	247	2	243	3	264	3	258	6	258	1
V _{DS on(-)}	V	-	2.89	2.08	.01	2.11	.07	2.07	.01	2.09	.01	2.05	.02	2.19	.02	2.15	.04	2.18	.02
V _{SD (-)}	V	.6	1.8	1.5	0	1.5	.04	1.4	.02	1.5	.02	1.4	.02	1.57	.03	1.51	.02	1.55	.03
T _{don}	ns	-	56	26	0.8	27	0.8	26	0.7	27	0.7	28	0.8	28	1	28	0	28	0
T _{doff}	ns	-	126	19	1.5	19	1	14	1.1	16	0.8	20	1.5	17	1.3	13	1.3	13	1.3
T _r	ns	-	124	49	1.8	50	5.3	45	2.2	41	2.2	44	1.5	41	1	45	1	46	0.5
T _d	ns	-	78	12	0.4	15	1.1	15	1.9	13	1.3	14	1.5	13	0.5	13	0.7	13	0.4

<Table IVA continued on next page>

TABLE IVA. (continued)

Group A - Parts irradiated without bias

Parameters		Spec. Limits		Initials		TDE (krads)		Annealing				Total Dose (krads)					
						50		24 hrs		168 hrs		100		200		300	
						mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd
VDSX(-)	V	100	-	Pass		Pass		Pass		Pass		Pass		Pass		Pass	
VGSth(-)	V	2	4	3.4	.03	3.5	.02	3.5	.02	3.5	.02	3.5	.03	3.6	.03	3.6	.03
IGSSF	nA	-	100	1.2	.03	1.5	.2	1.6	.03	1.3	0	1.5	.1	1.8	.1	1.8	.1
IGSSR	nA	-	100	.4	.07	.3	.06	.3	.03	.3	.06	.3	.06	.2	.03	.3	.04
IDSS1	mA	-	1	0	0	0	0	0	0	0	0	0	0	0	0	.01	0
IDSS2	uA	-	25	0	0	0	0	0	0	0	0	0	0	0	0	0	0
RDS on	mOhm	-	550	249	1	258	4	250	4	253	2	250	5	250	2	245	3
VDS cr(-)	V	-	2.89	2.08	.01	2.13	.03	2.12	.06	2.15	.01	2.10	.04	2.08	.02	2.09	.03
VSD(-)	V	.6	1.8	1.5	0	1.52	.05	1.58	.03	1.55	.02	1.47	.04	1.45	.02	1.48	.03
Tdon	ns	-	56	26	0.8	28	0.4	28	0.4	28	0	28	0	28	0	28	0
Tdoff	ns	-	126	19	1.5	14	0.9	14	1.1	14	1.3	13	1.9	13	1	14	0.7
T _r	ns	-	124	49	1.8	41	1	43	1.7	45	0.7	41	0.9	44	1.6	44	1.6
Td	ns	-	78	12	0.4	12	0.4	12	0.4	14	0.5	12	1.1	13	0.8	12	0.4

Note:

1/ The mean and standard deviation values were calculated over the four parts irradiated in this testing. The control sample remained constant throughout the testing and is not included in this table.

TABLE IVB: Summary of Electrical Measurements
after Total Dose Exposures and Annealing for FRL9130

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Group B - Parts irradiated under bias

Parameters	Units	Spec. Limits		Initials		Total Dose Exposure (krads)													
						2.5		5		7.5		10		15		20		30	
		min	max	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd
V _{DSS(-)}	V	100	-	Pass		Pass		Pass		Pass		Pass		Pass		Pass		Pass	
V _{Gsth(-)}	V	2	4	3.4	.03	3.4	.03	3.4	.03	3.4	.03	3.4	.03	3.4	.03	3.4	.03	3.5	.03
I _{GSSF}	μA	-	100	1.4	.06	1.3	.1	1.3	.1	1.5	.03	1.1	.03	1.2	.03	1.3	.03	1.3	.1
I _{GSSR}	nA	-	100	.3	.03	.4	.03	.3	.05	.3	.05	.4	.03	.3	.06	.3	.03	.3	.03
I _{DSS1}	μA	-	1000	.8	.7	1.1	1.0	1.1	1.0	1.2	1.0	1.2	1.0	1.2	1.0	1.3	1.0	1.3	1.0
I _{DSS2}	μA	-	25	.3	.3	.6	.6	.6	.6	.6	.6	.6	.6	.6	.6	.6	.6	.6	.6
R _{DS on}	mΩ	-	550	243	1	254	4	253	4	256	6	234	2	252	2	266	10	254	3
V _{DS on(-)}	V	-	2.89	2.05	.01	2.15	.05	2.11	.03	2.15	.05	2.05	.02	2.15	.02	2.19	.04	2.15	.03
V _{SD(-)}	V	.6	1.8	1.4	.01	1.5	.04	1.5	.03	1.55	.06	1.45	.02	1.50	.03	1.56	.02	1.51	.03
I _{don}	2/ ns	-	56	26	0.7	26	1.2	27	0.4	28	0.9	27	0.4	28	0.4	28	0.4	28	0.4
t _{doff}	2/ ns	-	126	16	0.8	17	1	17	0.9	16	0.8	20	0	18	1.9	15	1.6	15	1.6
T _r	2/ ns	-	124	50	9.2	48	5.6	44	0.8	42	1.4	46	3	40	0.4	44	2.4	43	2.1
T _d	2/ ns	-	78	12	2.5	13	1.9	13	2.6	15	1.6	14	0.4	11	0.8	13	0.8	12	0.4

<Table IVB continued on next page>

TABLE IVB. (continued)

1/, 2/

Group B - Parts irradiated under bias

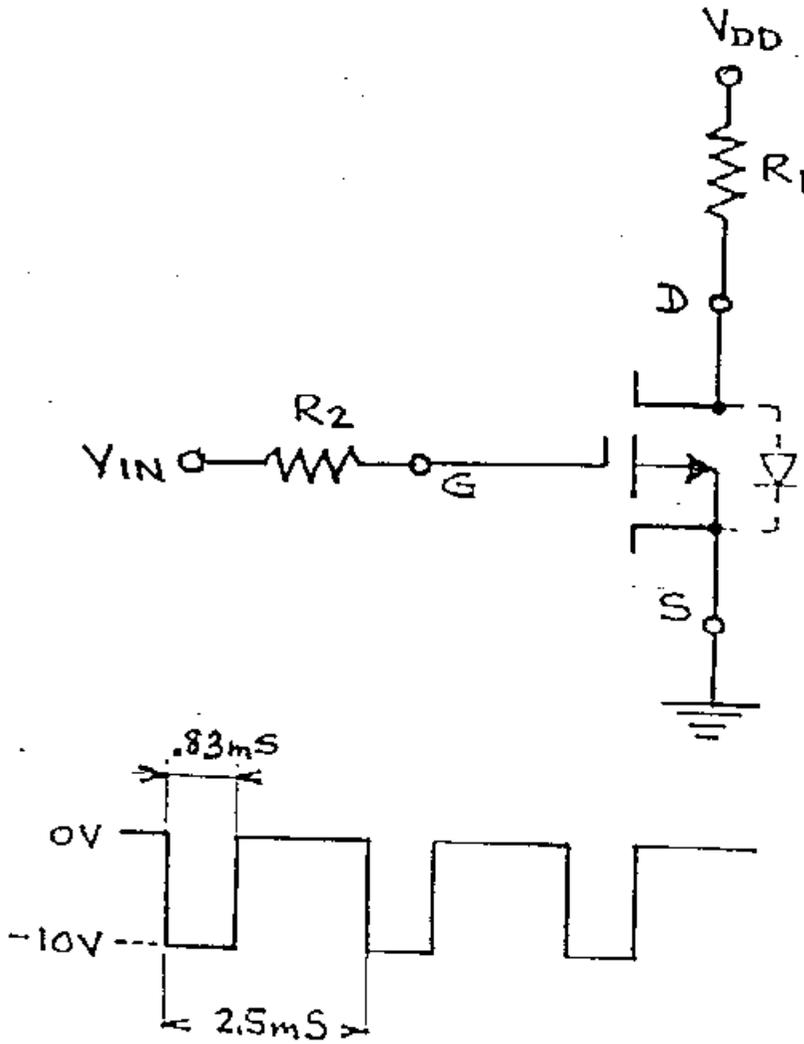
Parameters	Spec. Limits	Initials		TDE (krads)		Annealing				Total Dose (krads)							
				50		24 hrs		168 hrs		100		200		300			
				min	max	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd	mean	sd
VBDSS(-)	V	100	-	Pass		Pass		Pass		Pass		Pass		Pass		Pass	
VGStb(-)	V	2	4	3.4	.03	3.5	.03	3.5	.03	3.5	.03	3.5	.03	3.5	.03	3.6	.03
IGSSF	nA	-	100	1.4	.06	1.5	.2	1.3	.1	1.3	.1	2.2	.4	2.7	.2	3.2	.03
IGSSR	nA	-	100	.3	.03	.3	.05	.3	.05	.3	.05	.2	.03	.3	.03	.2	.03
IDSS1	uA	-	1000	.8	.7	1.3	1.0	1.3	1.0	1.2	1.0	1.3	1.0	1.3	1.0	1.2	1.0
IDSS2	uA	-	25	.3	.3	.6	.6	.6	.6	.6	.6	.6	.6	.6	.6	.5	.6
RDS on	mOhm	-	550	243	1	257	7	253	1	263	4	250	2	260	2	252	1
VDS on(-)	V	-	2.89	2.05	.01	2.15	.05	2.13	.01	2.27	.05	2.09	.03	2.18	.03	2.14	.02
VSD(-)	V	.5	1.8	1.4	.01	1.55	.04	1.53	.01	1.62	.04	1.48	.02	1.53	.03	1.49	.02
Tdon	2/ ns	-	56	26	0.7	28	0.5	27	0.4	28	0.5	28	0	28	0.5	28	0.4
Tdoff	2/ ns	-	126	16	0.8	13	1.3	16	1.8	15	1.1	14	0.8	15	0.5	14	0.9
Tr	2/ ns	-	124	50	9.2	41	1	41	1	44	2.3	41	2.2	41	1	44	1.3
Td	2/ ns	-	78	12	2.5	13	0.5	12	0	14	0.5	11	1	13	0.5	13	0

Notes:

1/ The mean and standard deviation values were calculated over the four parts irradiated in this testing. The control sample remained constant throughout the testing and is not included in this table.

2/ SN 221 did not initially pass the AC timing measurements (Tdon, Tdoff, Tr and Tf) after 7.5 krads, but passed twenty minutes later on retest. Also, SN 221 momentarily failed these tests after 50 krads, but again passed on retest. The values in Table IVB for these AC parameters after 7.5 and 50 krads reflect the passing, retested measurements.

Figure 1. Radiation Bias Circuit for FRL9130
(Test Group B only)



$$V_{IN} = -10V @ f = 400Hz \Rightarrow T = 2.5mS$$

$$V_{DD} = -28 \pm 0.5V$$

$$R_1 = 1K\Omega \pm 5\%, 1W$$

$$R_2 = 10K\Omega \pm 5\%, 1/4W$$

FIG. 1